

NEC
NEC Electronics Inc.

**μ PD78C18 Family
 μ PD78C17/C18/CP18
8-Bit, Single-Chip Microcontrollers
With A/D Converter**

September 1993

Description

The μ PD78C18 family is an expanded memory version of the μ PD78C14 family of 8-bit CMOS single-chip microcontrollers.

These microcontrollers integrate sophisticated on-chip peripheral functions normally provided by external components. Their internal 16-bit ALU and data paths, combined with a powerful instruction set and addressing capability, make the devices appropriate in data processing as well as control applications.

The devices integrate a 16-bit ALU, 32K-byte ROM, 1024-byte RAM, an eight-channel A/D converter, a multifunction 16-bit timer/event counter, two 8-bit timers, a USART, and two zero-crossing detect inputs on a single die, allowing their use in fast, high-end processing applications.

The μ PD78C18 family includes a 32K-byte mask ROM device, embedded with a customer program, a ROM-less device for use with up to 64K bytes of external memory, and a 32K-byte EPROM or OTP ROM device for prototyping and low-volume production. The μ PD78C18 may also be ordered with pullup resistors that are available as a mask option for ports A, B, and C.

Features

- CMOS technology
- 30 mA operating current (μ PD78C17/C18)
- Complete single-chip microcontroller
 - 16-bit ALU
 - 32K-byte ROM
 - 1024-byte RAM
- 40 I/O lines
- Pullup resistors for the mask option
 - Ports A, B, and C
 - μ PD78C18 device only
- Two zero-crossing detect inputs
- Two 8-bit timers
- Four edge-detection inputs (AN4-AN7)
- Expansion capabilities
 - 8085A-like bus
 - 64K-byte external memory address range
- Eight-channel, 8-bit A/D converter
 - Autoscan mode
 - Channel select mode
- Full-duplex USART (synchronous and asynchronous)
- 159 instructions
 - 16-bit arithmetic, multiply, and divide
 - HALT and STOP instructions
- 0.8 μ s instruction cycle time (15 MHz operation)
- Prioritized interrupt structure
 - Three external
 - Eight internal
- Standby function
- On-chip clock generator

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μPD78C18 Family**NEC****Ordering Information**

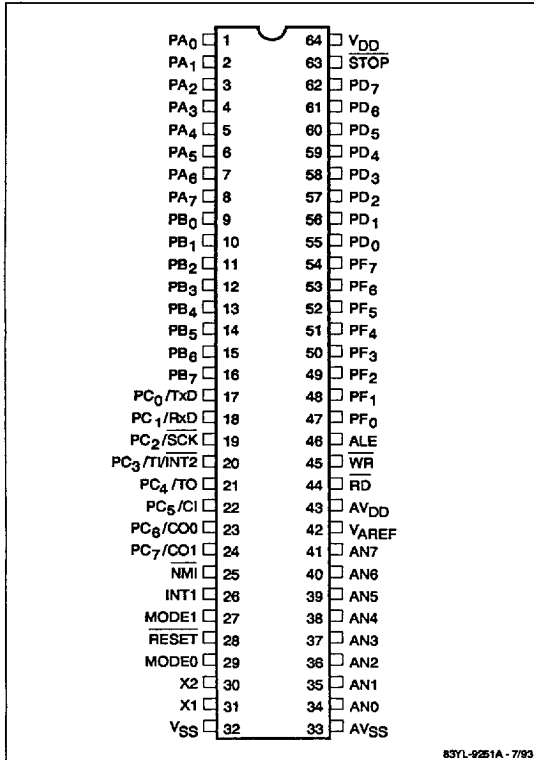
Part Number (Note 1)	Package	Package Drawing	Quality Grade (Note 3)
ROMless			
μPD78C17CW	64-pin SDIP	P64C-70-750A, C	Standard
GF-3BE	64-pin QFP (Note 2)	P64GF-100-3B8, 3BE-1	Standard
GF(A)-3BE			Special
GQ-36	64-pin QUIP	P64GQ-100-36	Standard
GQ(A)-36			Special
32K Mask ROM			
μPD78C18CW-xxx	64-pin SDIP	P64C-70-750A, C	Standard
GF-xxx-3BE	64-pin QFP (Note 2)	P64GF-100-3B8, 3BE-1	Standard
GF(A)-xxx-3BE			Special
GQ-xxx-36	64-pin QUIP	P64GQ-100-36	Standard
GQ(A)-xxx-36			Special
32K OTP ROM			
μPD78CP18CW	64-pin SDIP	P64C-70-750A, C	Standard
GF-3BE	64-pin QFP (Note 2)	P64GF-100-3B8, 3BE-1	Standard
GF(A)-3BE			Special
GQ-36	64-pin QUIP	P64GQ-100-36	Standard
GQ(A)-36			Special
32K UV EPROM			
μPD78CP18DW	64-pin SDIP w/window	P64C-70-750A, C	Standard
KB	64-pin ceramic LCC w/window	X64KW-100A-1	

Note:

- (1) xxx indicates ROM code suffix.
- (2) Engineering samples supplied in a ceramic QFP package
- (3) Special grade devices have the symbol (A) embedded in the part number

Pin Configurations

64-Pin Plastic QUIP or Plastic Shrink DIP

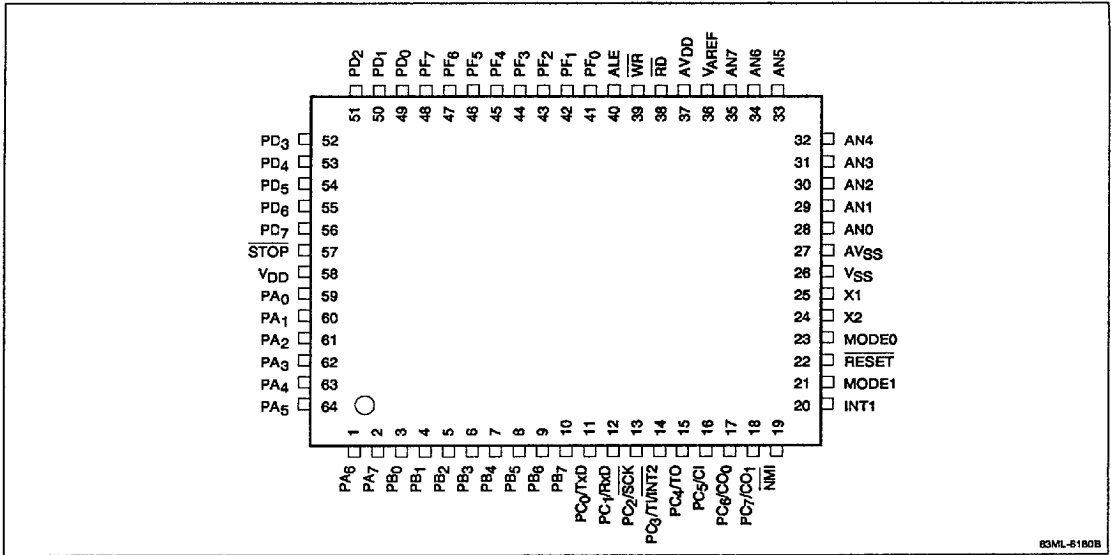


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μPD78C18 Family



64-Pin Plastic QFP or Ceramic LCC



83ML-6180B

Pin Identification

Symbol	Function
ALE	Address latch enable output
AN0-AN7	A/D converter analog inputs 0-7
INT1	Interrupt request 1 input
MODE0	Mode 0 input; I/O memory output
MODE1	Mode 1 input
NMI	Nonmaskable interrupt input
PA ₀ -PA ₇	Port A I/O lines 0-7
PB ₀ -PB ₇	Port B I/O lines 0-7
PC ₀ /TxD	Port C I/O line 0; transmit data output
PC ₁ /RxD	Port C I/O line 1; receive data input
PC ₂ /SCK	Port C I/O line 2; serial clock I/O
PC ₃ /TI/INT2	Port C I/O line 3; timer input; interrupt request 2 input
PC ₄ /TO	Port C I/O line 4; timer output
PC ₅ /CI	Port C I/O line 5; counter input
PC ₆ and PC ₇ / CO ₀ and CO ₁	Port C I/O lines 6 and 7; counter outputs 0 and 1
PD ₀ -PD ₇	Port D I/O; expansion memory address, data bus (bits AD ₀ -AD ₇)
PF ₀ -PF ₇	Port F I/O; expansion memory address, (bits AB ₈ -AB ₁₅)
RD	Read strobe output
RESET	Reset input
STOP	Stop mode control input
V _{AREF}	A/D converter reference voltage
WR	Write strobe output
X1 and X2	Crystal connections 1 and 2
AV _{DD}	A/D converter power supply voltage
AV _{SS}	A/D converter power supply ground
V _{DD}	+5 V power supply
V _{SS}	Ground
IC	Internal connection

Pin Functions

ALE (Address Latch Enable). The ALE output is used to strobe the address of PD₀-PD₇ into an external latch.

AN0-AN7 (Analog Inputs). AN0-AN7 are the eight analog inputs to the A/D converter. AN4-AN7 can also be used as digital inputs for falling edge detection.

CI (Counter Input). CI is the external pulse input to the timer/event counter.

CO₀ and CO₁ (Counter Outputs). CO₀ and CO₁ are programmable waveform outputs from the timer/event counter.

INT1 (Interrupt Request 1). INT1 is a rising edge-triggered, maskable interrupt input, as well as an ac-input, zero-crossing detection terminal.

INT2 (Interrupt Request 2). INT2 is a falling edge-triggered, maskable interrupt input, as well as an ac-input, zero-crossing detection terminal.

If the optional pullup resistor is specified for this pin on the μPD78C18, the zero-crossing detection circuitry will not function.

MODE0 and MODE1 (Mode). For the μPD78C17, the size of the externally installed memory can be selected as 4K, 16K, or 63K bytes by setting the MODE0 and MODE1 pins.

For the μPD78C18, the MODE0 pin is set to 0 (logic low). The MODE1 pin is pulled high with a pullup resistor.

For the μPD78C17/C18, an external pullup resistor to V_{DD} is required, if the mode pin is to be a logic high. The value of this pullup resistor, R, is dependent on t_{CYC} and is calculated as follows: R in kΩ is $4 \leq R \leq 0.4 t_{CYC}$, where t_{CYC} is in ns units.

NMI (Nonmaskable Interrupt). NMI is a falling edge, Schmitt-triggered nonmaskable interrupt input.

PA₀-PA₇ (Port A). Port A is an 8-bit three-state port. Each bit is independently programmable as either input or output. The reset signal causes all lines of port A to be inputs. Pullup resistors are available as a mask option on the μPD78C18.

PB₀-PB₇ (Port B). Port B is an 8-bit three-state port. Each bit is independently programmable as either input or output. The reset signal causes all lines of port B to be inputs. Pullup resistors are available as a mask option on the μPD78C18.

PC₀-PC₇ (Port C). Port C is an 8-bit three-state port. Each bit is independently programmable as either input or output. Alternatively, the lines of port C can be used as control lines for the USART, interrupts, and timer. The reset signal causes all lines of port C to be inputs. Pullup resistors are available as a mask option on the μPD78C18.

μ PD78C18 Family**NEC**

PD₀-PD₇ (Port D). Port D is an 8-bit three-state port. It can be programmed as either 8 bits of input or 8 bits of output. When external expansion memory is used, port D functions as the multiplexed address/data bus.

PF₀-PF₇ (Port F). Port F is an 8-bit three-state port. Each bit is independently programmable as either input or output. When external expansion memory is used, port F outputs the high-order address bits.

$\overline{\text{RD}}$ (Read Strobe). The strobe signal, when output for read operation of external memory, operates as follows. The signal is high, except during a data read machine cycle. It becomes a high output impedance when the $\overline{\text{RESET}}$ signal is low or when the device is in hardware stop mode.

$\overline{\text{RESET}}$ (Reset). When the Schmitt-triggered $\overline{\text{RESET}}$ input goes low, it initializes the device.

RxD (Receive Data). RxD is the serial data input terminal.

$\overline{\text{SCK}}$ (Serial Clock). $\overline{\text{SCK}}$ is the serial clock output when the internal clock is used. $\overline{\text{SCK}}$ is the input for the serial clock when the external clock is used.

$\overline{\text{STOP}}$ (Stop Mode Control Input). A low-level input on $\overline{\text{STOP}}$ (Schmitt-triggered input) stops the system clock oscillator.

TI (Timer Input). TI is the timer input terminal.

TO (Timer Output). The output of TO is a square wave with a frequency determined by the timer/counter.

TxD (Transmit Data). TxD is the serial data output terminal.

V_{AREF} (A/D Converter Reference). V_{AREF} functions as an input pin for the A/D converter reference voltage and as the control pin for A/D converter operation.

$\overline{\text{WR}}$ (Write Strobe). The strobe signal, when output for the write operation of external memory, operates as follows. The signal is high, except during a data write machine cycle. It becomes a high output impedance when the $\overline{\text{RESET}}$ signal is low or when the device is in hardware stop mode.

X1 and X2 (Crystal Connections). X1 and X2 are the system clock crystal oscillator terminals. X1 is also the input for an external clock.

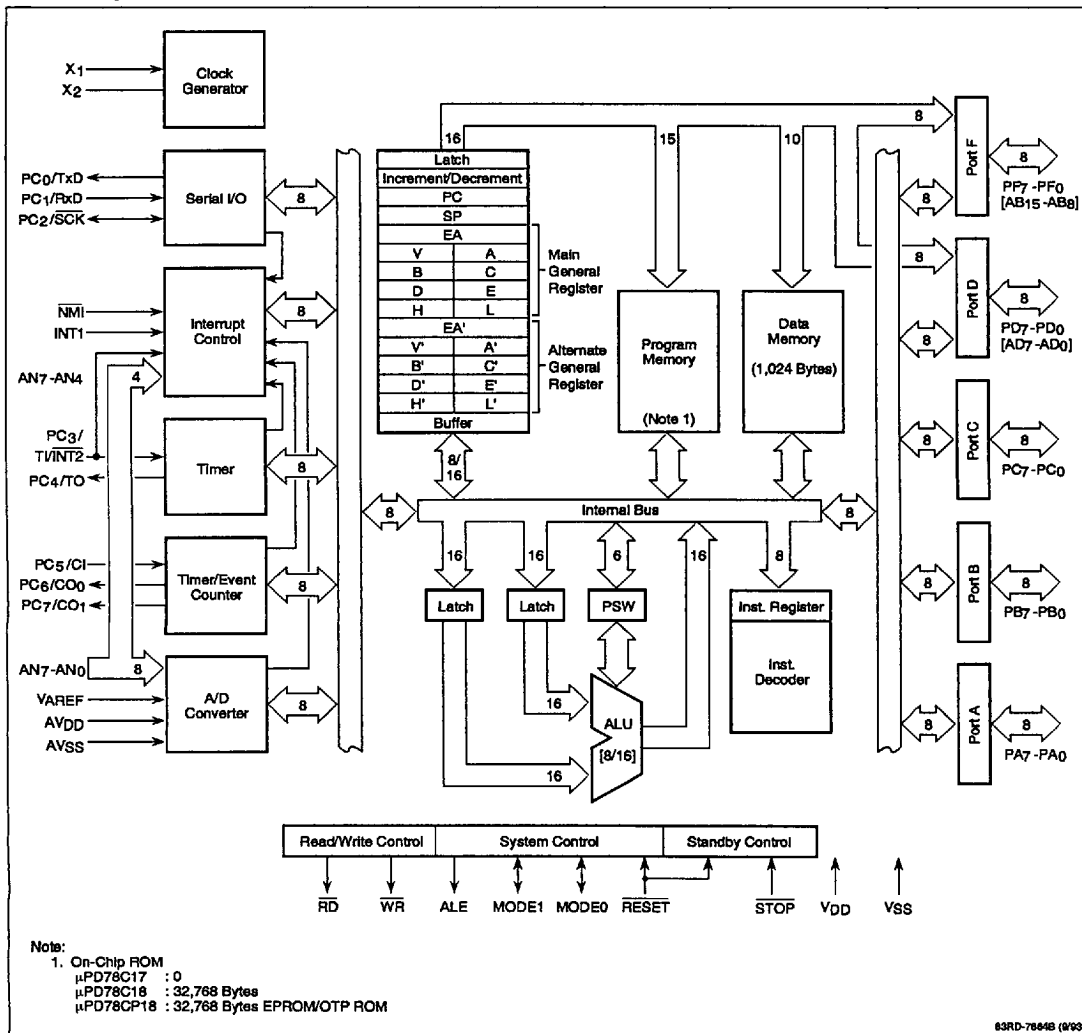
V_{DD} (A/D Converter Power). This is the power supply voltage for the A/D converter.

V_{SS} (A/D Converter Ground). V_{SS} is the ground potential for the A/D converter power supply.

V_{DD} (Power Supply). V_{DD} is the +5-volt power supply.

V_{SS} (Ground). V_{SS} is the ground potential for the +5-volt device power supply.

Block Diagram



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63RD-78848 (9/93)

μPD78C18 Family

FUNCTIONAL DESCRIPTION

Memory Map

The μPD78C18 family can directly address up to 64K bytes of memory. Except for the on-chip ROM (or PROM) and RAM (FC00H-FFFFH), any memory location can be used as ROM or RAM. The memory maps, shown in figures 1 through 3, define the 0 to 64K-byte memory space for the μPD78C18 family.

The μPD78CP18 can be programmed by software to have 4K, 8K, 16K, or 32K bytes of internal program memory. This programming is transparent to a ROM-based device, allowing easy transfer of code.

Figure 1. Memory Map (μPD78C17)

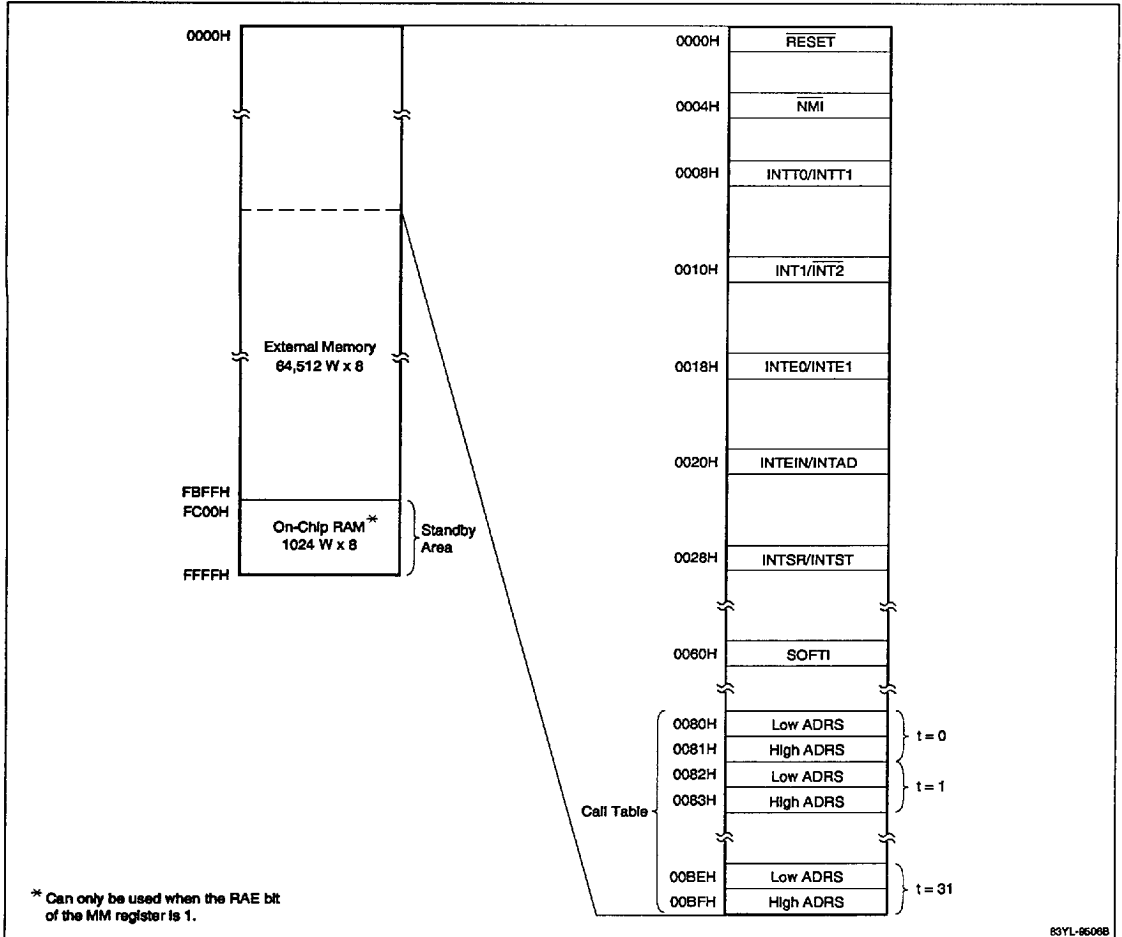
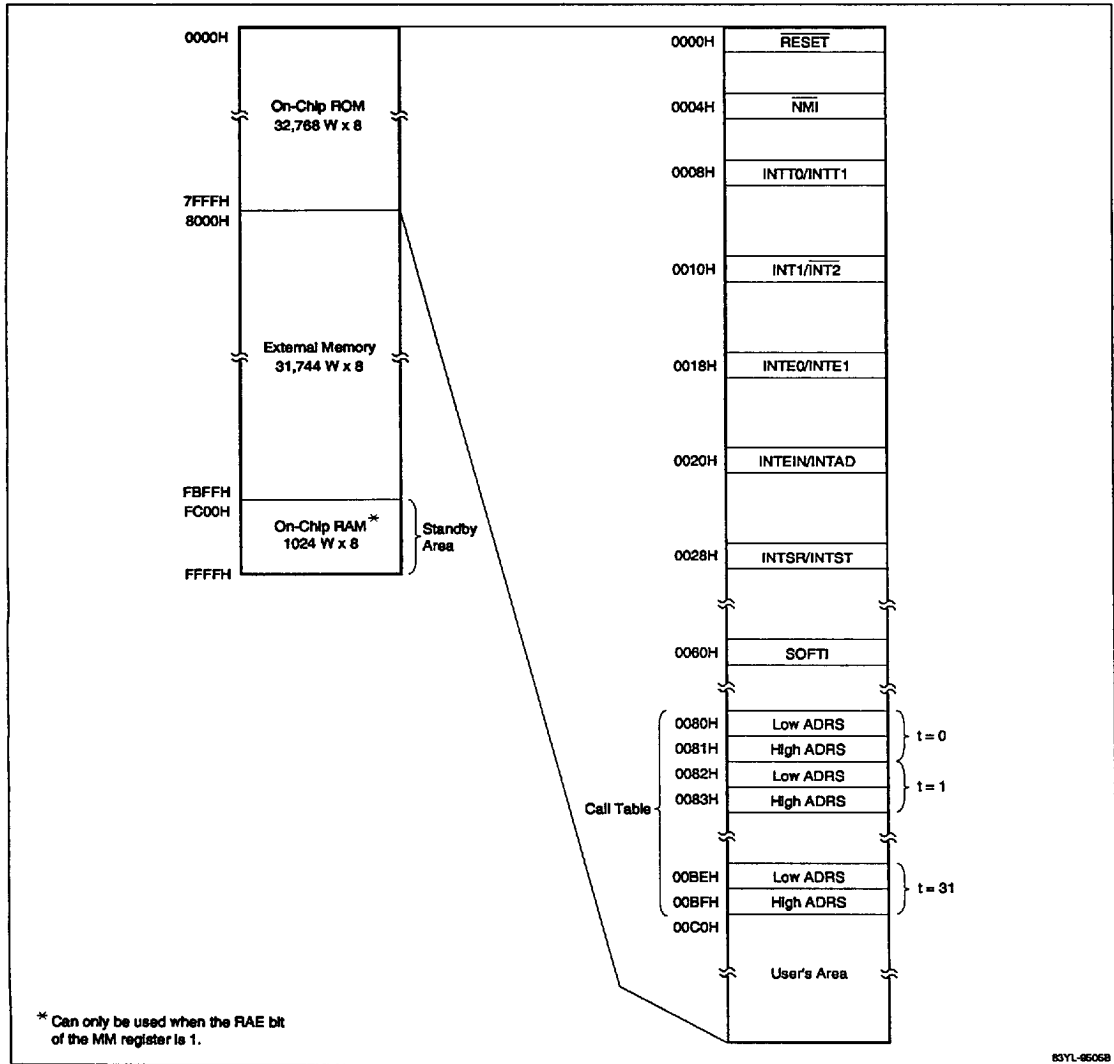


Figure 2. Memory Map (μPD78C18)

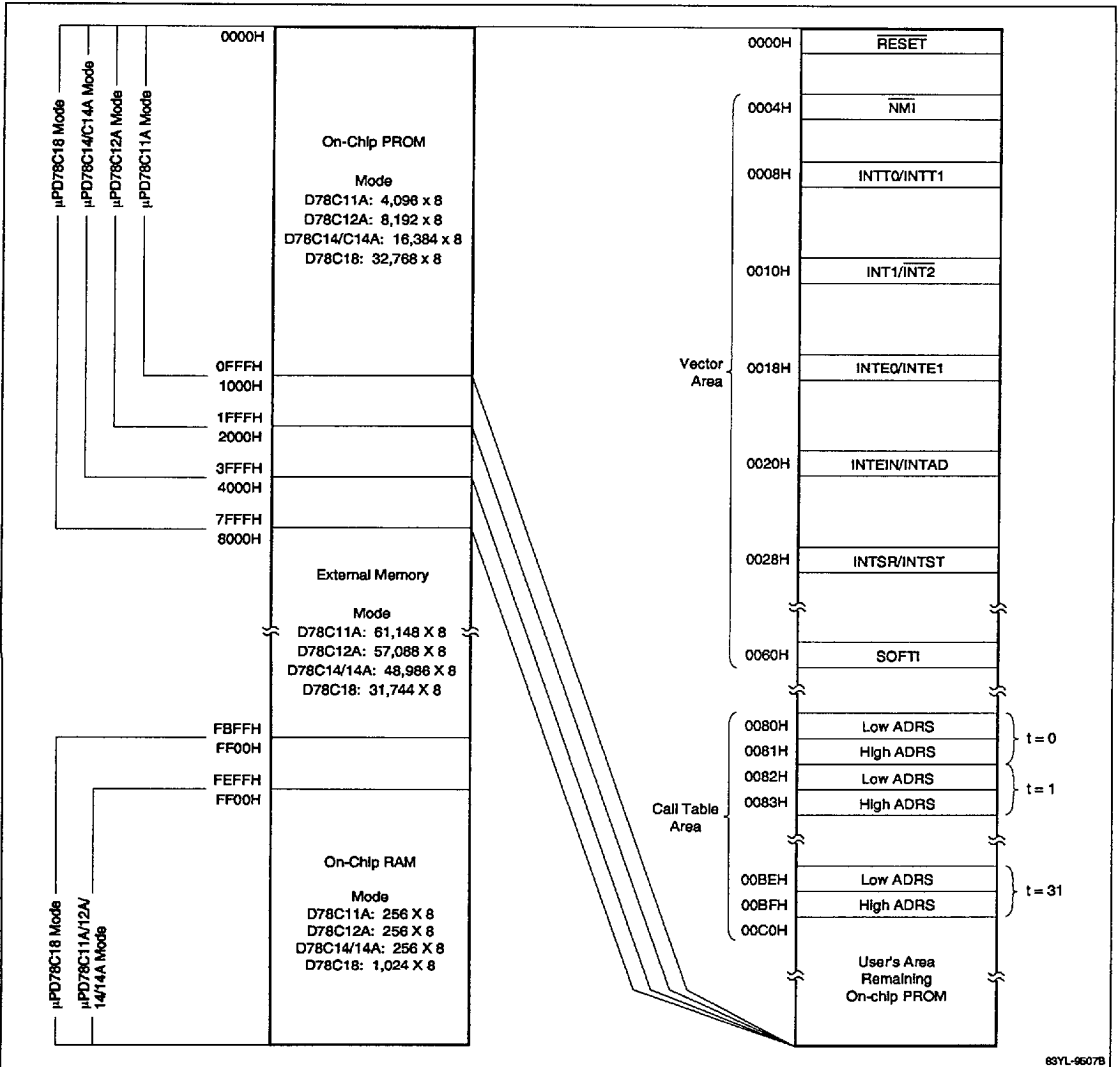


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μPD78C18 Family



Figure 3. Memory Map (μPD78C18)



63YL-9507B

Input/Output

The μ PD78C18 family has 40 digital I/O lines, consisting of five 8-bit ports (ports A, B, C, D, and F), and four digital input lines (AN4-AN7).

Analog Input Lines. AN0-AN7 are configured as analog input lines for the on-chip A/D converter. Lines AN4-AN7 can be used as digital input lines for falling edge detection.

Port A, Port B, Port C, and Port F. Each line of these ports can be individually programmed as an input or output. When used as I/O ports, all have latched outputs and high impedance inputs. On the μ PD78C18, pullup resistors are available as a mask option for ports A, B, and C.

Port D. Port D can be programmed as a byte input or a byte output.

Control Lines. Under software control, each line of port C can be configured individually as a control line for the serial interface, timer, and timer/counter or as an I/O port.

Memory Expansion. In addition to the single-chip operation mode, the μ PD78C18 family has four memory expansion modes. Under software control, port D can provide a multiplexed low-order address and data bus; port F can provide a high-order address bus. Table 1 shows the relationship between the memory expansion modes and the pin configurations of port D and port F.

Table 1. Memory Expansion Modes and Port Configurations

Memory Expansion	Port	Port Configuration
None	Port D	I/O port
	Port F	I/O port
256 bytes	Port D	Multiplexed address/data bus
	Port F	I/O port
4K bytes	Port D	Multiplexed address/data bus
	Port F (PF ₀ -PF ₃)	Address bus
	Port F (PF ₄ -PF ₇)	I/O port
16K bytes	Port D	Multiplexed address/data bus
	Port F (PF ₀ -PF ₅)	Address bus
	Port F (PF ₆ -PF ₇)	I/O port
32K/48K/56K/60K bytes (Note 1)	Port D	Multiplexed address/data bus
	Port F	Address bus

Note:

(1) Set according to bits MM7 to MM5.

μPD78C18 Family



Timers

The two 8-bit timers can be programmed independently or cascaded as a 16-bit timer. The timer can be set by software to increment at intervals of four machine cycles ($0.8 \mu\text{s}$ at 15 MHz operation) or 128 machine cycles ($25.6 \mu\text{s}$ at 15 MHz), or to increment on receipt of a pulse at TI. Figure 4 is the block diagram for the timer.

Timer/Event Counter

The 16-bit multifunctional timer/event counter, shown in figure 5, can be used for the following operations:

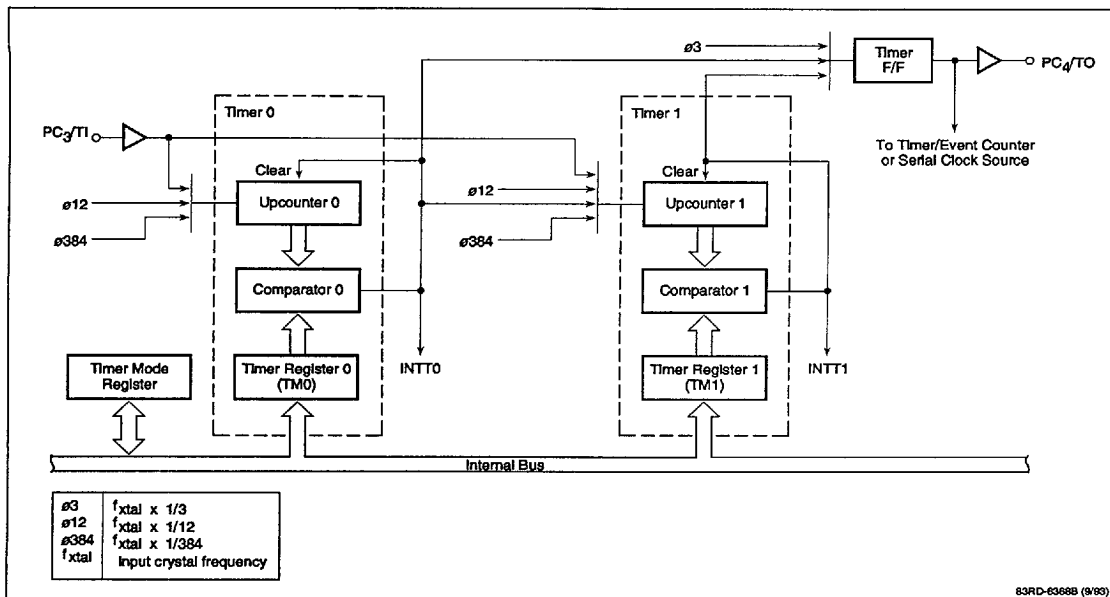
- Interval timing
- External event counting
- Frequency measurement
- Pulse-width measurement
- Programmable frequency and duty cycle waveform output
- Single-pulse output

8-Bit A/D Converter

The 8-bit A/D converter provides the following:

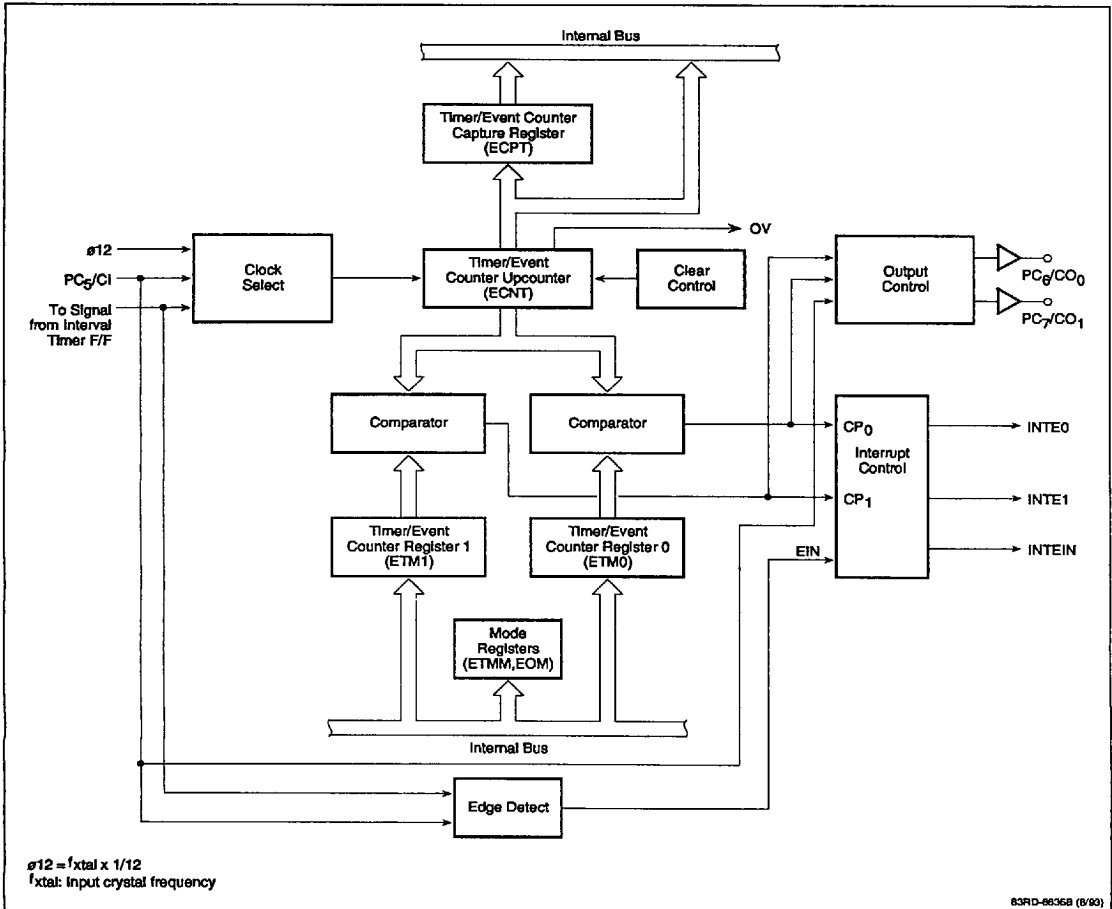
- Eight input channels
- Four conversion result registers
- Two powerful operation modes
 - Autoscan
 - Channel select
- Successive approximation technique
- Absolute accuracy: $0.6\% \text{ FSR} \pm 1/2 \text{ LSB}$
- Conversion range: 0 to 5 V
- Conversion time: $38.4 \mu\text{s}$
- Interrupt generation

Figure 4. Timer Block Diagram



83RD-63688 (9/93)

Figure 5. Block Diagram for the Timer/Event Counter



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Analog/Digital Converter

The μPD78C18 family features an 8-bit, high-speed, high accuracy A/D converter. The A/D converter is comprised of a 256-resistor ladder and a successive approximation register (SAR). There are four conversion result registers (CR0-CR3).

The eight-channel analog input can be operated in two different modes. In the select mode, the conversion value of one analog input is sequentially stored in CR0-CR3. In the scan mode, either the upper four channels or the lower four channels may be specified. The four channels specified will be consecutively selected and the conversion results stored sequentially in the four conversion result registers.

Figure 6 is the block diagram for the A/D converter. To stop the operation of the A/D converter and reduce the power consumption, set $V_{AREF} = 0V$.

Interrupt Structure

There are 12 interrupt sources in the μPD78C18 family. Three are external and nine are internal interrupt sources. Table 2 shows 11 interrupt sources divided into seven priority levels, where IRQ0 is the highest and IRQ6 is the lowest. See figure 7.

Figure 6. A/D Converter Block Diagram

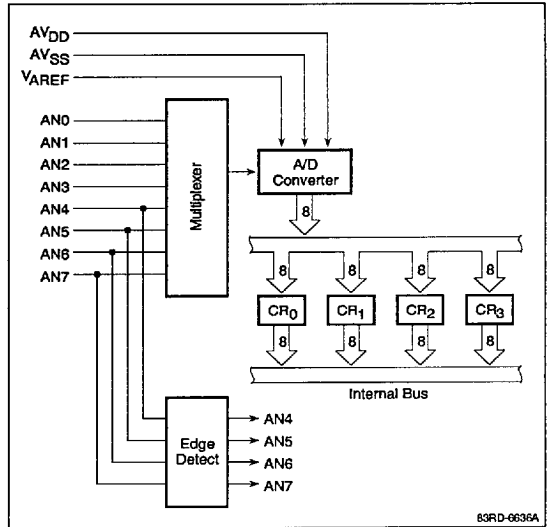


Figure 7. Interrupt Structure Block Diagram

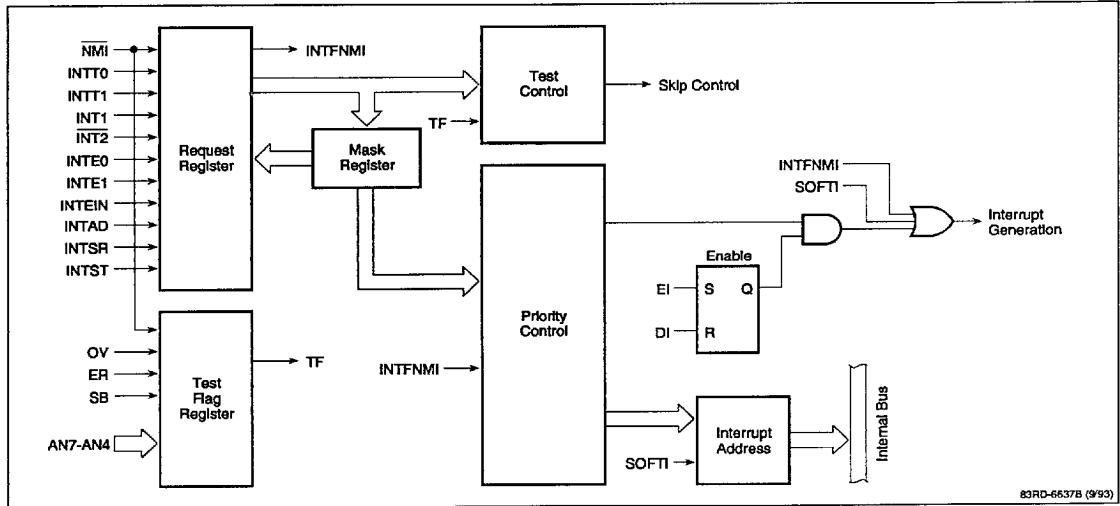


Table 2. Interrupt Sources

Interrupt Request	Interrupt Address	Type of Interrupt	Internal/External
IRQ0	4	NMI (nonmaskable interrupt)	External
IRQ1	8	INTT0, INTT1 (coincidence signals from timers 0, 1)	Internal
IRQ2	16	INT1, $\overline{\text{INT2}}$ (maskable interrupts)	External
IRQ3	24	INTE0, INTE1 (coincidence signals from timer/event counter)	Internal
IRQ4	32	INTEIN (falling signal of CI or TO into the timer/event counter)	Internal or External
		INTAD (A/D converter interrupt)	Internal
IRQ5	40	INTSR (serial receive interrupt)	Internal
		INST (serial send interrupt)	
IRQ6	96	SOFTI instruction	Internal

Standby Modes

The μPD78C18 family has two standby modes: HALT and STOP.

HALT Mode. The HALT mode reduces power consumption to 50% of normal operating requirements, while maintaining the contents of on-chip registers, RAM, and control status. The system clock and on-board peripherals continue to operate, but the CPU stops executing instructions. The HALT mode is initiated by executing the HLT instruction and can be released by any nonmasked interrupt or by RESET.

STOP Mode. The STOP mode reduces power consumption to less than 0.1% of normal operating requirements. There are two stop modes: type A and type B.

Type A is initiated by executing a STOP instruction. If V_{DD} is held above 2.5 V, the contents of the on-board RAM are saved. The oscillator is stopped. The stop mode can be released by an input on $\overline{\text{NMI}}$ or RESET. The user can program oscillator stabilization time up to 52.4 ms via timer 1. By checking the standby flag (SB), the user can determine whether the processor has been in the standby mode or has been powered up.

Type B is initiated by inputting a low level on the $\overline{\text{STOP}}$ input. The RAM contents are saved if V_{DD} is held above 2.5 V. The oscillator is stopped. The stop mode is released by raising $\overline{\text{STOP}}$ to a high level. The oscillator stabilization time is fixed at 52.4 ms; instructions will automatically begin executing at location 0, 52.4 ms after STOP is raised. You can increase the stabilization time by holding RESET low for the required time period.

Universal Serial Interface

The serial interface can operate in one of three modes: synchronous, asynchronous, and I/O interface. I/O interface mode transfers data most significant bit (MSB)

first, for ease of interfacing to certain NEC peripheral devices. Synchronous and asynchronous modes transfer data least significant bit (LSB) first. Synchronous operation offers two modes of data reception: search and nonsearch. In the search mode, data is transferred one bit at a time from the serial register to the receive buffer. This allows a software search for a synchronous character. In the nonsearch mode, data going from the serial register to the transmit buffer is transferred eight bits at a time. Figure 8 shows the universal serial interface block diagram.

Zero-Crossing Detector

The INT1 and $\overline{\text{INT2}}$ (common to T1 and PC₃) terminals can detect the zero-crossing point of low-frequency AC signals. When driven directly, these pins respond as a normal digital input. Figure 9 shows the zero-crossing detection circuitry.

The zero-crossing detection capability allows you to make the 50-60 Hz power signal the basis for system timing and to control voltage phase-sensitive devices.

To use the zero-crossing detection mode, an AC signal of 1.0 to 1.8 V (peak to peak) and a maximum frequency of 1 kHz is coupled through an external capacitor to the INT1 and $\overline{\text{INT2}}$ pins.

For the INT1 pin, the internal digital state is sensed as a 0 until the rising edge crosses the average DC level. It then becomes a 1 and an INT1 interrupt is generated.

For the $\overline{\text{INT2}}$ pin, the state is sensed as a 1 until the falling edge crosses the average DC level. It then becomes a 0 and $\overline{\text{INT2}}$ is generated.

Figure 8. Universal Serial Interface Block Diagram

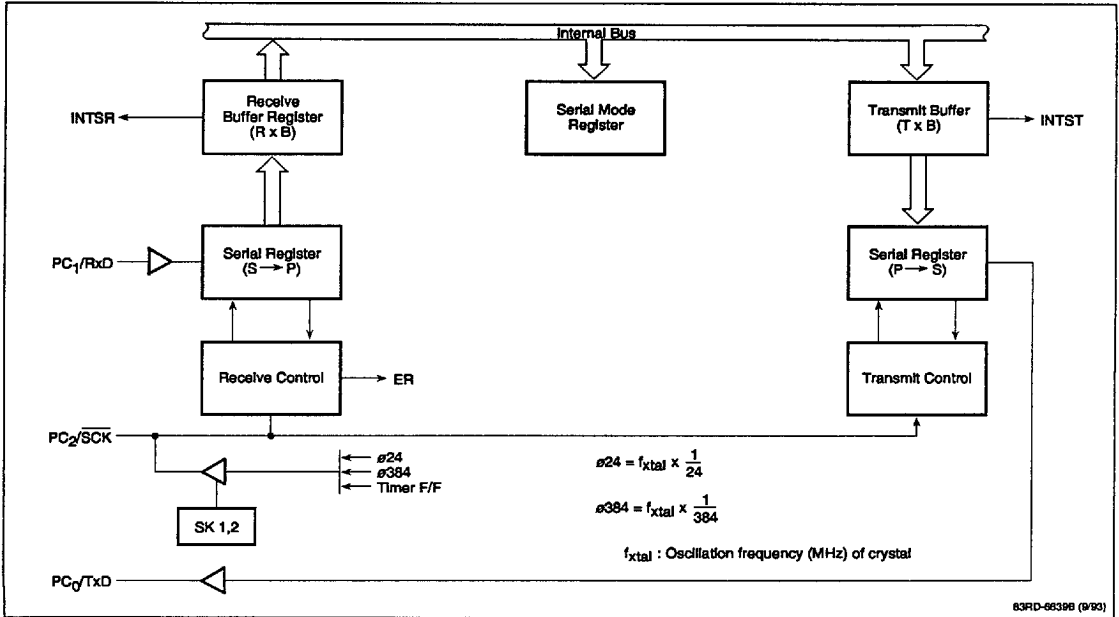
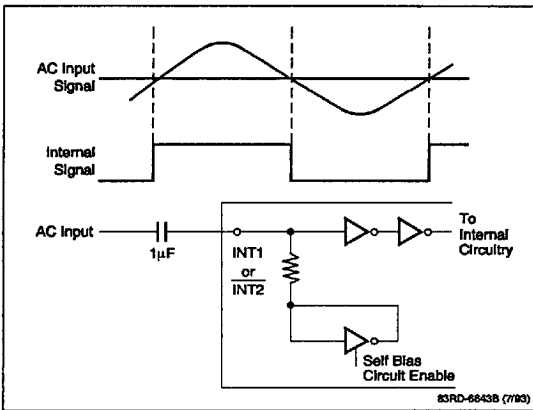


Figure 9. Zero-Crossing Detection Circuit



ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings, μPD78C17/C18

T _A = 25°C	
Power supply voltage, V _{DD}	-0.5 to +7.0 V
AV _{DD}	AV _{SS} to V _{DD} + 0.5 V
AV _{SS}	-0.5 to +0.5 V
V _{PP} (μPD78CP18 only)	-0.5 to +13.5 V
Input voltage, V _I	-0.5 to V _{DD} + 0.5 V
Output voltage, V _O	-0.5 to V _{DD} + 0.5 V
Output current, low; I _{OL}	
Each output pin	4.0 mA
Total	100 mA
Output current, high; I _{OH}	
Each output pin	-2.0 mA
Total	-50 mA
Reference input voltage, V _{AREF}	-0.5 to AV _{DD} + 0.3 V
Operating temperature, T _{OPR} (f _{X_{TAL}} ≤ 15 MHz)	-40 to +85°C
Storage temperature, T _{STG}	-65 to +150°C

Exposure to Absolute Maximum Ratings for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The device should be operated within the limits specified under DC and AC Characteristics.

Oscillation Characteristics

T_A = -40 to +85°C; V_{DD} = AV_{DD} = 5 V ± 10%; V_{SS} = AV_{SS} = 0 V; V_{DD} - 0.8 V ≤ AV_{DD} ≤ V_{DD}; 3.4 V ≤ V_{AREF} ≤ AV_{DD}

Resonator	Recommended Circuit	Parameter	Recommended Values			Unit	Conditions
			Min	Typ	Max		
Ceramic resonator (Note 1) or crystal oscillator (XTAL) (Note 2)	(Note 3)	Oscillation frequency (f _{OX})	4		15	MHz	A/D converter not used
			5.8		15	MHz	A/D converter used
External clock	(Note 4)	X1 input frequency (f _X)	4		15	MHz	A/D converter not used
			5.8		15	MHz	A/D converter used
		X1 input, rise, fall time (t _r , t _f)	0		20	ns	
		X1 input low- and high-level width (t _{φL} , t _{φH})	20		250	ns	

- Notes:**
- (1) Refer to the Resonator and Capacitance Requirements table for the recommended ceramic resonators.
 - (2) When using a crystal oscillator, it should be a parallel-resonant, fundamental mode, "AT cut" crystal. Capacitors C1 and C2 are required for frequency stability. The values of C1 and C2 (C1 = C2) can be calculated from the load capacitance (C_L), specified by the crystal manufacturer:
 - (3) For XTAL, see the Recommended XTAL or Ceramic Resonator Oscillation Circuit Diagram.
 - (4) See the Recommended External Clock Diagram.

$$C_L = \frac{C_1 \times C_2}{C_1 + C_2} + C_S$$

Where C_S is any stray capacitance in parallel with the crystal.

Capacitance

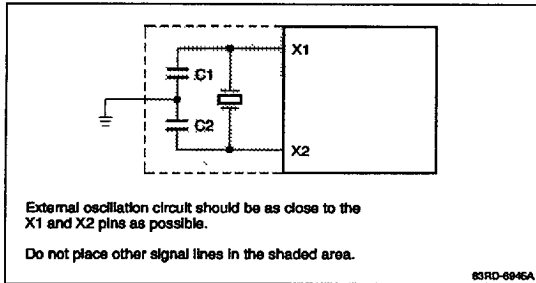
T_A = 25°C; V_{DD} = V_{SS} = 0 V

Parameter	Symbol	Max	Unit	Conditions
Input capacitance	C _I	10	pF	f _c = 1 MHz; unmeasured pins returned to 0 V
Output capacitance	C _O	20	pF	
I/O capacitance	C _{IO}	20	pF	

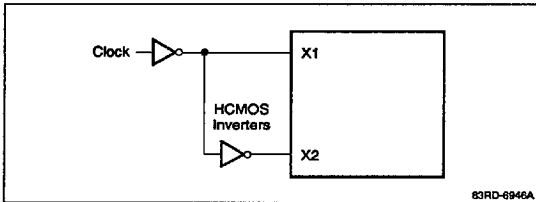
μPD78C18 Family



Recommended XTAL or Ceramic Resonator Oscillation Circuit Diagram



Recommended External Clock Diagram



Resonator and Capacitance Requirements

$T_A = -40$ to $+85^\circ\text{C}$

Manufacturer	Product Number	C1, C2 (pF)
Murata	CSA15.00MX001	22
	CST15.00MXW001	None required
	CSA10.0MT	30
	CST10.0MTW	None required
	CSA8.00MT	30
	CST8.00MTW	None required
TDK	FCR15.0MC	None required
	FCR10.0	None required
	FCR8.0	None required

DC Characteristics $T_A = -40$ to $+85^\circ\text{C}$; $V_{DD} = AV_{DD} = +5.0\text{ V} \pm 10\%$; $V_{SS} = AV_{SS} = 0\text{ V}$

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage, low	V_{IL1}	0		0.8	V	All except the Note 1 inputs
	V_{IL2}	0		$0.2 V_{DD}$	V	Note 1 inputs
Input voltage, high	V_{IH1}	2.2		V_{DD}	V	All except X1, X2, and the Note 1 inputs
	V_{IH2}	$0.8 V_{DD}$		V_{DD}	V	X1, X2, and the Note 1 inputs
Output voltage, low	V_{OL}			0.45	V	$I_{OL} = 2.0\text{ mA}$
Output voltage, high	V_{OH}	$V_{DD} - 1.0$			V	$I_{OH} = -1.0\text{ mA}$
		$V_{DD} - 0.5$			V	$I_{OH} = -100\ \mu\text{A}$
Input current	I_{I1}			± 200	μA	INT1 (Note 2); T1 (PC ₃) (Note 3); $0\text{ V} \leq V_I \leq V_{DD}$
Input leakage current	I_{L1}			± 10	μA	All except INT1; T1 (PC ₃); $0\text{ V} \leq V_I \leq V_{DD}$
				± 1	μA	AN7-0; $0\text{ V} \leq V_I \leq V_{DD}$ (μ PD78C17(A)/C18(A)/CP18(A) only)
Output leakage current	I_{LO}			± 10	μA	$0\text{ V} \leq V_O \leq V_{DD}$
AV_{DD} supply current	AI_{DD1}		0.5	1.3	mA	$f = 15\text{ MHz}$
	AI_{DD2}		10	20	μA	Stop mode
V_{DD} supply current	I_{DD1}		16	30	mA	Normal operation; $f = 15\text{ MHz}$
	I_{DD2}		7	13	mA	Halt mode; $f = 15\text{ MHz}$
Data retention voltage	V_{DDDR}	2.5			V	Stop mode
Data retention current	I_{DDDR}		1	15	μA	$V_{DDDR} = 2.5\text{ V}$ (Note 4)
			10	50	μA	$V_{DDDR} = 5.0\text{ V} \pm 10\%$ (Note 4)
Pullup resistor	R_L	17	27	75	k Ω	Ports A, B, C; $3.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$; $V_I = 0\text{ V}$ (μ PD78C18/C18(A) only)

Notes:

- (1) Inputs RESET, STOP, NMI, SCK, INT1, T1, and AN4-AN7.
- (2) Assuming ZCM register is set to self-bias.
- (3) Assuming ZCM register is set to self-bias and the MCC register is set to the control mode.
- (4) Hardware/software stop mode and assuming ZCM register is set so that self-bias is not selected.

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μPD78C18 Family**NEC****AC Characteristics** $T_A = -40$ to $+85^\circ\text{C}$; $V_{DD} = AV_{DD} = +5.0\text{V} \pm 10\%$; $V_{SS} = AV_{SS} = 0\text{V}$

Parameter	Symbol	Min	Max	Unit	Conditions
RESET pulse width high, low	t_{RSH}, t_{RSL}	10		μs	
NMI pulse width high, low	t_{NIH}, t_{NIL}	10		μs	
X1 input cycle time	t_{CYC}	66	250	ns	
			167	ns	(Note 1)
Address setup to ALE ↓	t_{AL}	30		ns	(Notes 2, 3)
Address hold from ALE ↓	t_{LA}	35		ns	(Notes 2, 3)
Address to \overline{RD} ↓ delay time	t_{AR}	100		ns	(Notes 2, 3)
\overline{RD} ↓ to address floating	t_{AFR}		20	ns	(Note 3)
Address to data input	t_{AD}		250	ns	(Notes 2, 3)
ALE ↓ to data input	t_{LDR}		135	ns	(Notes 2, 3)
\overline{RD} ↓ to data input	t_{RD}		120	ns	(Notes 2, 3)
ALE ↓ to \overline{RD} ↓ delay time	t_{LR}	15		ns	(Notes 2, 3)
Data hold time from \overline{RD} ↑	t_{RDH}	0		ns	(Note 3)
\overline{RD} ↑ to ALE ↑ delay time	t_{RL}	80		ns	(Notes 2, 3)
\overline{RD} width low	t_{RR}	215		ns	Data read (Notes 2, 3)
		415		ns	Opcode fetch (Notes 2, 3)
ALE width high	t_{LL}	90		ns	(Notes 2, 3)
$\overline{M1}$ setup time to ALE ↓	t_{ML}	30		ns	(Note 3)
$\overline{M1}$ hold time after ALE ↓	t_{LM}	35		ns	(Note 3)
$\overline{IO}/\overline{M}$ setup time to ALE ↓	t_{IL}	30		ns	(Note 3)
$\overline{IO}/\overline{M}$ hold time after ALE ↓	t_{LI}	35		ns	(Note 3)
Address to \overline{WR} ↓ delay	t_{AW}	100		ns	(Notes 2, 3)
ALE ↓ to data output	t_{LDW}		180	ns	(Notes 2, 3)
\overline{WR} ↓ to data output	t_{WD}		100	ns	(Note 3)
ALE ↓ to \overline{WR} ↓ delay time	t_{LW}	15		ns	(Notes 2, 3)
Data setup time to \overline{WR} ↑	t_{DW}	165		ns	(Notes 2, 3)
		127		ns	(Note 1)
Data hold time from \overline{WR} ↑	t_{WDH}	60		ns	(Notes 2, 3)
\overline{WR} ↑ to ALE ↑ delay time	t_{WL}	80		ns	(Notes 2, 3)
\overline{WR} width low	t_{WW}	215		ns	(Notes 2, 3)

Notes:

- (1) μPD78CP18 only.
- (2) Load capacitance $C_L = 100\text{ pF}$.
- (3) Values are for 15 MHz operation. For operation at other frequencies, refer to the table labeled Bus Timing Dependent on t_{CYC} .

Serial Operation

Parameter	Symbol	Min	Max	Unit	Conditions
SCK cycle time	t _{CYK}	0.8		μs	SCK input (Notes 1, 3)
		0.4		μs	SCK input (Note 2)
		1.6		μs	SCK output (Note 3)
SCK width low	t _{KKL}	335		ns	SCK input (Notes 1, 3)
		160		ns	SCK input (Note 2)
		700		ns	SCK output (Note 3)
SCK width high	t _{KKH}	335		ns	SCK input (Notes 1, 3)
		160		ns	SCK input (Note 2)
		700		ns	SCK output (Note 3)
RxD setup time to SCK ↑	t _{RXK}	80		ns	(Note 1)
RxD hold time after SCK ↑	t _{KRX}	80		ns	(Note 1)
SCK ↓ TxD delay time	t _{KTX}		210	ns	(Note 1)

Notes:

- (1) 1 x baud rate in asynchronous, synchronous, and I/O interface modes.
- (2) 16 x baud rate or 64 x baud rate in asynchronous mode.
- (3) f_{X_{TAL}} = 15 MHz.

Zero-Crossing Characteristics

Parameter	Symbol	Min	Max	Unit	Condition
Zero-crossing detection input	V _{ZX}	1	1.8	VAC _{p-p}	AC coupled 60 Hz sine wave
Zero-crossing accuracy	A _{ZX}		±135	mV	
Zero-crossing detection input frequency	f _{ZX}	0.05	1	kHz	

A/D Converter Characteristics

T_A = -40 to +85°C; V_{DD} = +5.0 V ±10%; V_{SS} = AV_{SS} = 0 V; V_{DD} - 0.5 V ≤ AV_{DD} ≤ V_{DD}; 3.4 V ≤ V_{AREF} ≤ AV_{DD}

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Resolution		8			bits	
Absolute accuracy (Note 1)				±0.4	%FSR	T _A = -10 to +70°C; 66 ns ≤ t _{CYC} ≤ 170 ns; 4.0 V ≤ V _{AREF} ≤ AV _{DD}
				±0.6	%FSR	66 ns ≤ t _{CYC} ≤ 170 ns; 4.0 V ≤ V _{AREF} ≤ AV _{DD}
				±0.8	%FSR	66 ns ≤ t _{CYC} ≤ 170 ns; 3.4 V ≤ V _{AREF} ≤ AV _{DD}
Conversion time	t _{CONV}	576			t _{CYC}	66 ns ≤ t _{CYC} ≤ 110 ns
		432			t _{CYC}	110 ns ≤ t _{CYC} ≤ 170 ns
Sampling time	t _{SAMP}	96			t _{CYC}	66 ns ≤ t _{CYC} ≤ 110 ns
		72			t _{CYC}	110 ns ≤ t _{CYC} ≤ 170 ns
Analog input voltage	V _{IAN}	0		V _{AREF}	V	
Analog input impedance	R _{AN}		1000		MΩ	
Reference voltage	V _{AREF}	3.4		AV _{DD}	V	
V _{AREF} current	I _{AREF1}		1.5	3.0	mA	Operation mode
	I _{AREF2}		0.7	1.5	mA	Stop mode

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μPD78C18 Family



A/D Converter Characteristics (cont)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
AVDD supply current	AlDD1		0.5	1.3	mA	Operation mode; fXTAL = 15 MHz
	AlDD2		10	20	μA	Stop mode

Notes:

(1) Quantizing error (±1/2 LSB) is not included.

(2) FSR = full-scale resolution.

Bus Timing Dependent on tCYC

Symbol	Min/Max (ns)	Calculation Formula
tTIH, tTIL	Min	6T (TI input - PC3)
tCHH, tCHL (Note 2)	Min	6T (TI input - PC5)
tC2H, tC2L (Note 3)	Min	48T (TI Input - PC5)
t1H, t1L	Min	36T (INT1)
t2H, t2L	Min	36T (INT2)
tANH, tANL	Min	36T (AN4-AN7)
tAL	Min	2T - 100
tLA	Min	T - 30
tAR	Min	3T - 100
tAD	Max	7T - 220
tLDR	Max	5T - 200
tRD	Max	4T - 150
tLR	Min	T - 50
tRL	Min	2T - 50
tRR	Min	4T - 50 (Data read)
	Min	7T - 50 (Opcode fetch)
tLL	Min	2T - 40
tML	Min	2T - 100
tLM	Min	T - 30
tIL	Min	2T - 100
tLI	Min	T - 30
tAW	Min	3T - 100
tLDW	Max	T + 110
		T + 130 (Note 7)

Symbol	Min/Max (ns)	Calculation Formula
tLW	Min	T - 50
tDW	Min	4T - 100/4T - 140 (Note 7)
tWDH	Min	2T - 70
tWL	Min	2T - 50
tWW	Min	4T - 50
tCYC	Min	24T (SCK output)
	Min	12T (SCK input) (Note 1)
	Min	6T (Note 6)
tKKL	Min	12T - 100 (SCK output)
	Min	5T + 5 (SCK input) (Note 1)
	Min	2.5T + 5 (Note 6)
tKKH	Min	12T - 100 (SCK output)
	Min	5T + 5 (SCK input) (Note 1)
	Min	2.5T + 5 (Note 6)

Notes:

- (1) 1 x baud rate in asynchronous, synchronous, and I/O interface modes.
- (2) Event counter mode.
- (3) Pulse width measurement mode.
- (4) $T = t_{CYC} = 1/f_{XTAL}$.
- (5) The items not included in this list are independent of oscillator frequency (fXTAL).
- (6) 16 x baud rate or 64 x baud rate in asynchronous mode
- (7) μPD78CP18/CP18(A) only.

Data Memory Stop Mode Data Retention Characteristics

 $T_A = -40$ to $+85^\circ\text{C}$

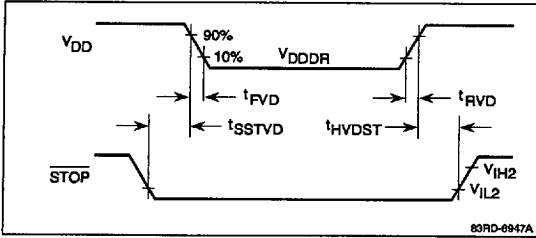
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Data retention power supply voltage	V_{DDDR}	2.5		5.5	V	
Data retention power supply current	I_{DDDR}		1	15	μA	$V_{DDDR} = 2.5\text{ V}$
			15	50	μA	$V_{DDDR} = 5.0\text{ V} \pm 10\%$
V_{DD} rise, fall time	t_{RVD}, t_{FVD}	200			μs	
STOP setup time to V_{DD}	t_{SSTVD}	$12T + 0.5$			μs	
STOP hold time from V_{DD}	t_{HVDST}	$12T + 0.5$			μs	

μPD78C18 Family

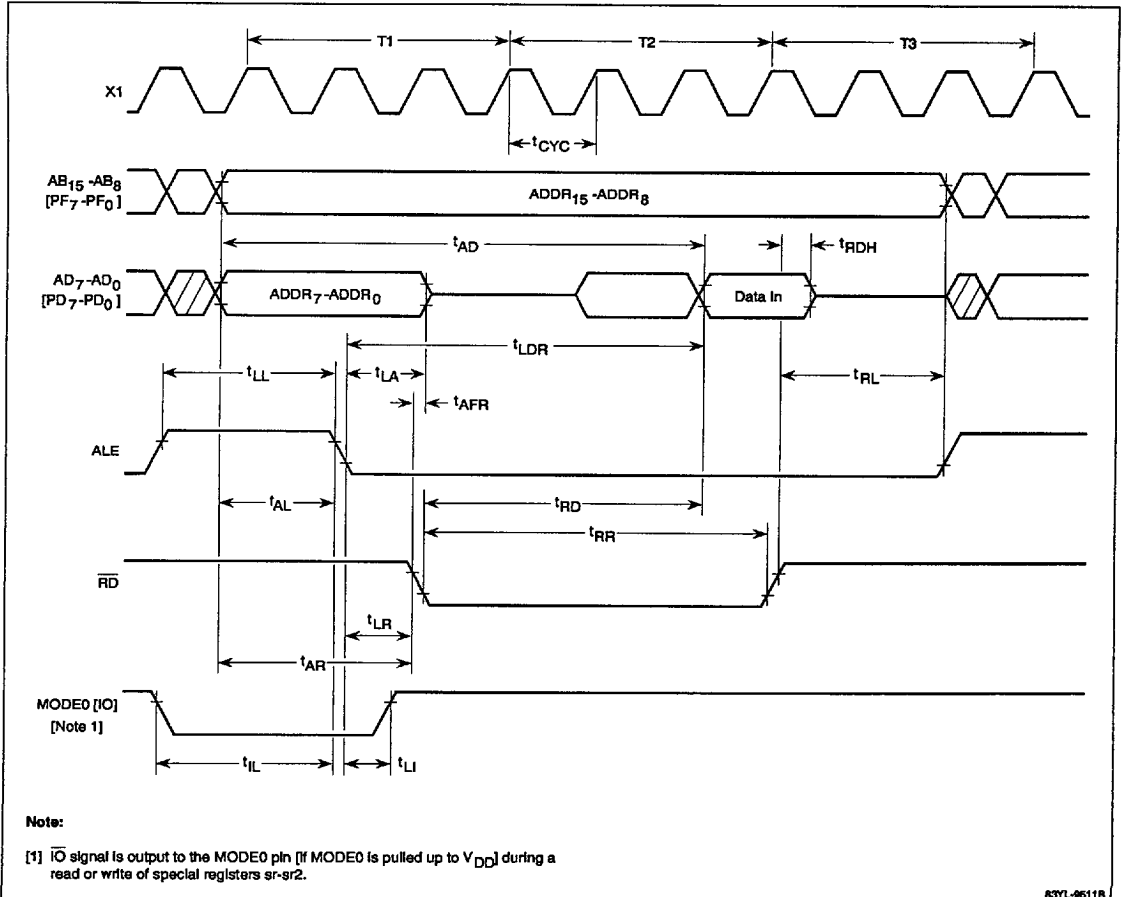


Timing Waveforms

Data Retention

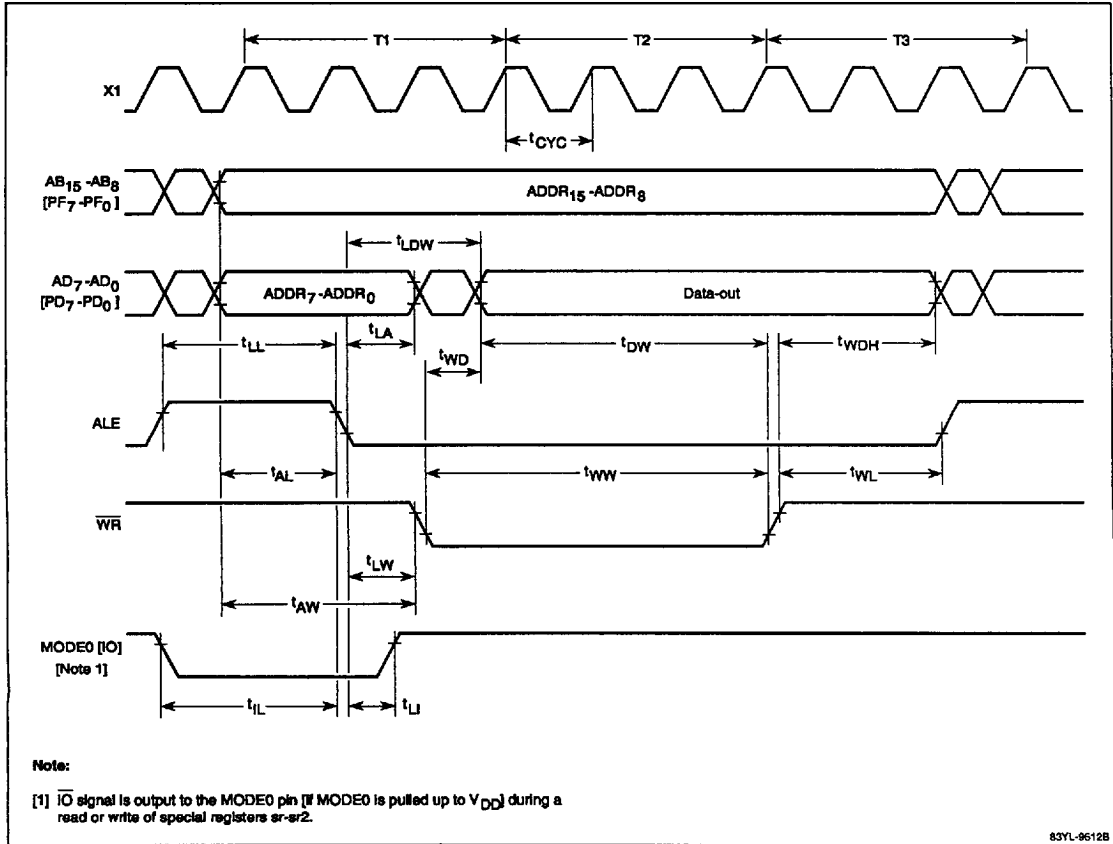


Data Read Operation



Timing Waveforms (cont)

Data Write Operation



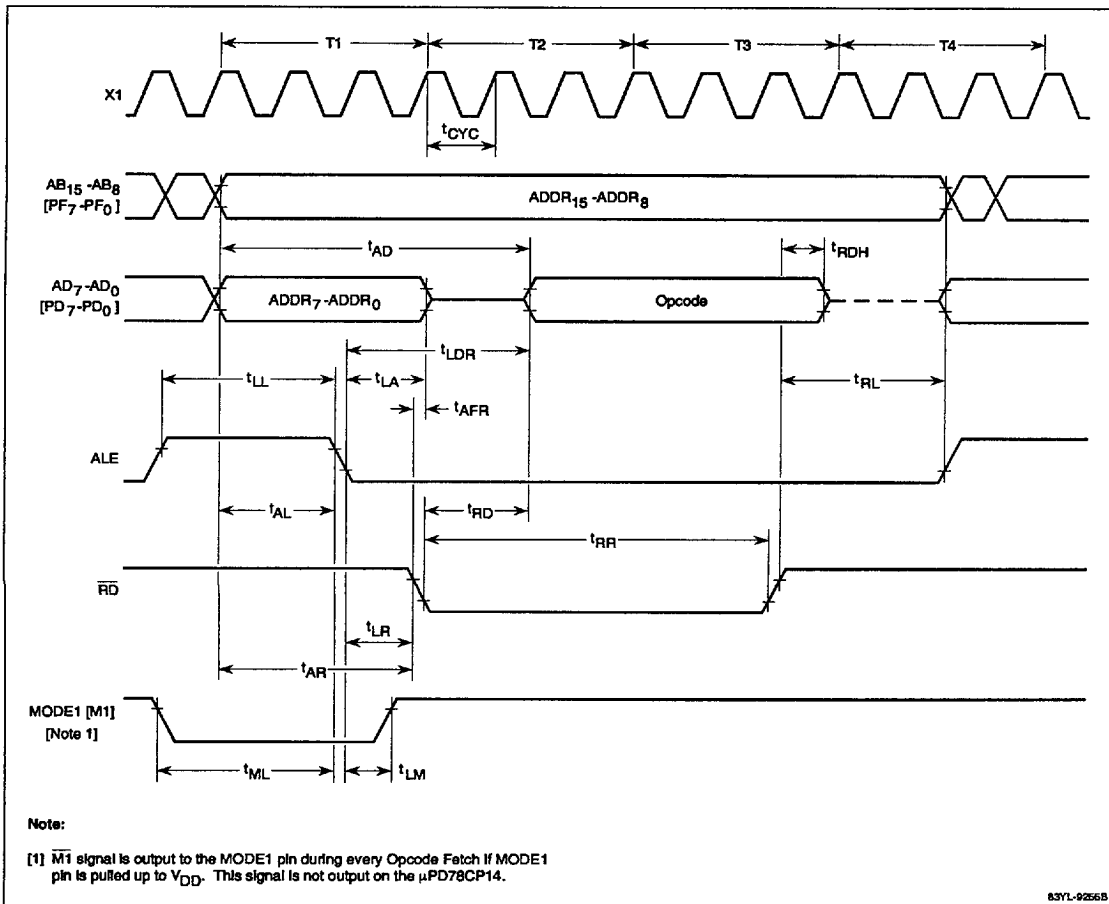
2b

μPD78C18 Family

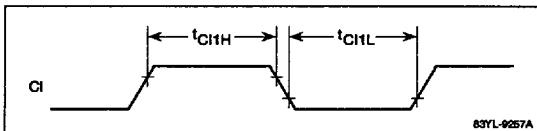


Timing Waveforms (cont)

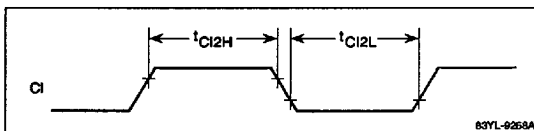
Opcode Fetch Operation



**Timer/Event Counter Input:
Event Counter Mode**

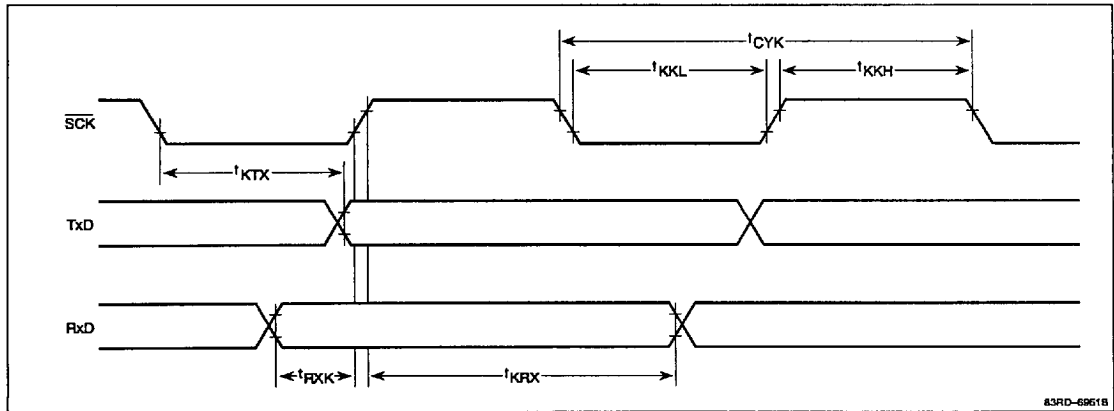


**Timer/Event Counter Input:
Pulse Width Measurement Mode**



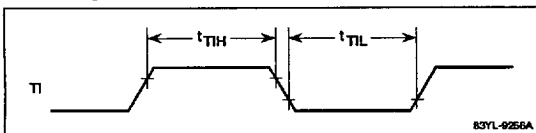
Timing Waveforms (cont)

Serial Operation Transmit/Receive

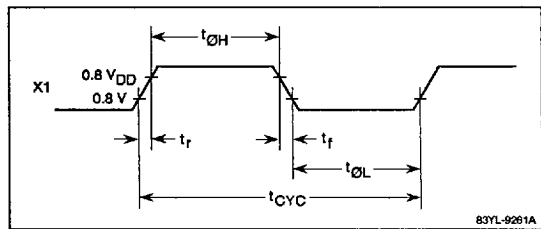


2b

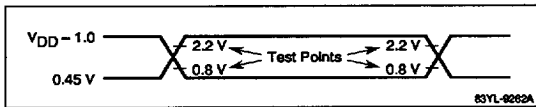
Timer Input



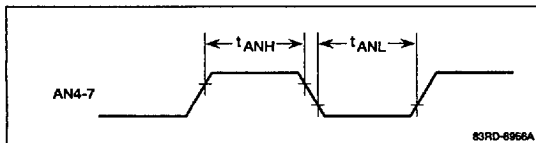
External Clock



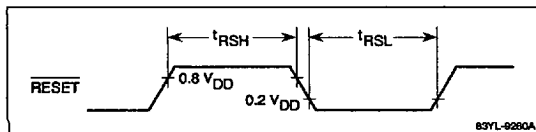
AC Timing Test Points



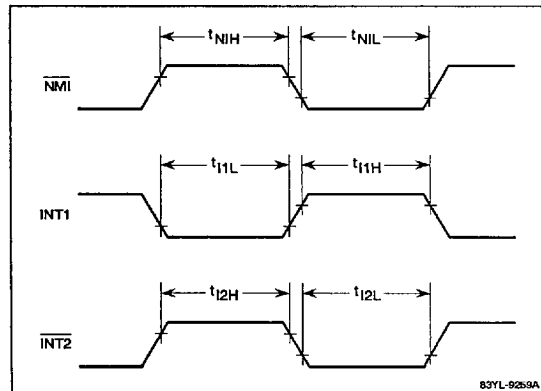
AN4-AN7 Edge Detection



RESET Input



Interrupt Input



μPD78C18 Family**NEC****μPD78CP18 PROGRAMMING**

In the μPD78CP18, the mask ROM of the μPD78C18 family is replaced by a one-time programmable ROM (OTP ROM) or a reprogrammable, ultraviolet erasable ROM (UV EPROM). The ROM is 32,768 by 8 bits and can be programmed using a general-purpose PROM writer with a μPD27C256A programming mode. Refer to tables 3 through 5 and the DC and AC Programming Characteristics tables for specific information applicable to programming the μPD78CP18.

Table 3. Pin Functions during EPROM Programming

Pin	Function	Description
PA ₀ -PA ₇	A ₀ -A ₇	Low-order 8-bit address
PF ₀	A ₈	High-order 7-bit address
NMI	A ₉	
PF ₂ -PF ₆	A ₁₀ -A ₁₄	
PD ₀ -PD ₇	D ₀ -D ₇	Data input/output
PB ₆	\overline{CE}	Chip enable input
PB ₇	\overline{OE}	Output enable input
RESET	\overline{RESET}	PROM programming mode requires a low voltage on this pin
Mode 0	Mode 0	Enter PROM programming mode by applying a high voltage to this pin
Mode 1	Mode 1	Enter PROM programming mode by applying a low voltage to this pin
STOP	V _{pp}	High-voltage input (write/verify) high level (read)

Table 4. Summary of Operation Modes for EPROM Programming

Operation Mode	\overline{CE}	\overline{OE}	V _{pp}	V _{DD}	\overline{RESET}	MODE0	MODE1
Program write	L	H	+12.5 V	+6 V	L	H	L
Program verify	H	L	+12.5 V	+6 V	L	H	L
Program inhibit	H	H	+12.5 V	+6 V	L	H	L
Read	L	L	+5 V	+5 V	L	H	L
Output disable	L	H	+5 V	+5 V	L	H	L
Standby	H	L/H	+5 V	+5 V	L	H	L

Notes:

(1) The \overline{CE} , \overline{OE} , V_{pp}, and V_{DD} pins are all compatible with the μPD27C256A pins.

Caution: When V_{pp} is set to +12.5 V and V_{DD} is set to +6 V, you cannot set both \overline{CE} and \overline{OE} to low level (L).

Table 5. Recommended Connections for Unused Pins (EPROM Programming Mode)

Pin	Recommended Connection Method
INT1	Connect to V _{SS}
X1	Connect to V _{SS}
X2	Leave this pin disconnected
AN0-AN7	Connect to V _{SS}
VAREF	Connect to V _{SS}
AV _{DD}	Connect to V _{SS}
AV _{SS}	Connect to V _{SS}
Remaining pins	Connect each pin via a resistor to V _{SS}

PROM Write Procedure

- (1) Connect the $\overline{\text{RESET}}$ pin, the MODE1 pin, and A₁₄ pin to a low level and connect the MODE0 pin to a high level. Connect all unused pins as recommended in Table 5.
- (2) Apply +6 V to the V_{DD} pin and +12.5 V to the V_{PP} pin.
- (3) Provide the initial address.
- (4) Provide write data.
- (5) Provide 1-ms program pulse (active low) to the $\overline{\text{CE}}$ pin.
- (6) This bit is now verified with a pulse (active low) to the $\overline{\text{OE}}$ pin. If the data has been written, proceed to step 8; if not, repeat steps 4 to 6. If the data cannot be correctly written after 25 attempts, go to step 7.
- (7) Classify as defective and stop write operation.
- (8) Provide write data and supply program pulse (for additional writing) for 3 ms times the number of repeats performed between steps 4 to 6.
- (9) Increment the address.
- (10) Repeat steps 4 to 9 until the end address.

PROM Read Procedure

- (1) Connect the $\overline{\text{RESET}}$ pin and the MODE1 pin to a low level and connect the MODE0 pin to a high level.
- (2) Apply +5 V to the V_{DD} and V_{PP} pins.
- (3) Input the address of the data to be read to pins A₀-A₁₄.
- (4) Read mode is entered with a pulse (active low) on both the CE and OE pins.
- (5) Data is output to the D₀-D₇ pins.

EPROM Erasure

Data in an EPROM is erased by exposing the quartz window in the ceramic package to light having a wavelength shorter than 400 nm, including ultraviolet rays, direct sunlight, and fluorescent light. To prevent unintentional erasure, mask the window.

Typically, data is erased by 254-nm ultraviolet rays. A minimum lighting level of 15W-s/cm² (ultraviolet ray intensity x exposure time) is required to completely erase written data. Erasure by an ultraviolet lamp rated at 12 mW/cm² takes approximately 15 to 20 minutes. Remove any filter on the lamp and place the device within 2.5 cm of the lamp tubes,

μPD78C18 Family**μPD78CP18 DC Programming Characteristics** $T_A = 25 \pm 5^\circ\text{C}$; MODE1 = V_{IL} ; MODE0 = V_{IH} ; $V_{SS} = 0\text{ V}$

Parameter	Symbol	Symbol*	Min	Typ	Max	Unit	Condition
High-level input voltage	V_{IH}	V_{IH}	2.2		$V_{DDP} + 0.3$	V	
Low-level input voltage	V_{IL}	V_{IL}	-0.3		0.8	V	
Input leakage current	I_{LIP}	I_{LI}			± 10	μA	$0 \leq V_1 \leq V_{DDP}$
High-level output voltage	V_{OH}	V_{OH}	$V_{DD} - 1.0$			V	$I_{OH} = -1.0\text{ mA}$
Low-level output voltage	V_{OL}	V_{OL}			0.45	V	$I_{OL} = 2.0\text{ mA}$
Output leakage current	I_{LO}				± 10	μA	$0 \leq V_O \leq V_{DDP}$; $\overline{OE} = V_{IH}$
V_{DDP} power voltage	V_{DDP}	V_{CC}	5.75	6.0	6.25	V	Program memory write mode
			4.5	5.0	5.5	V	Program memory read mode
V_{PP} power voltage	V_{PP}	V_{PP}	12.2	12.5	12.8	V	Program memory write mode
				$V_{PP} = V_{DDP}$		V	Program memory read mode
V_{DDP} power current	I_{DD}	I_{CC}		5.0	50	mA	Program memory write mode
				5.0	50	mA	Program memory read mode; $CE = V_{IL}$; $V_1 = V_{IH}$
V_{PP} power current	I_{PP}	I_{PP}			30	mA	Program memory read mode; $CE = V_{IL}$; $\overline{OE} = V_{IH}$
				1	100	μA	Program memory write mode

* Corresponding symbols of the μPD27C256A.

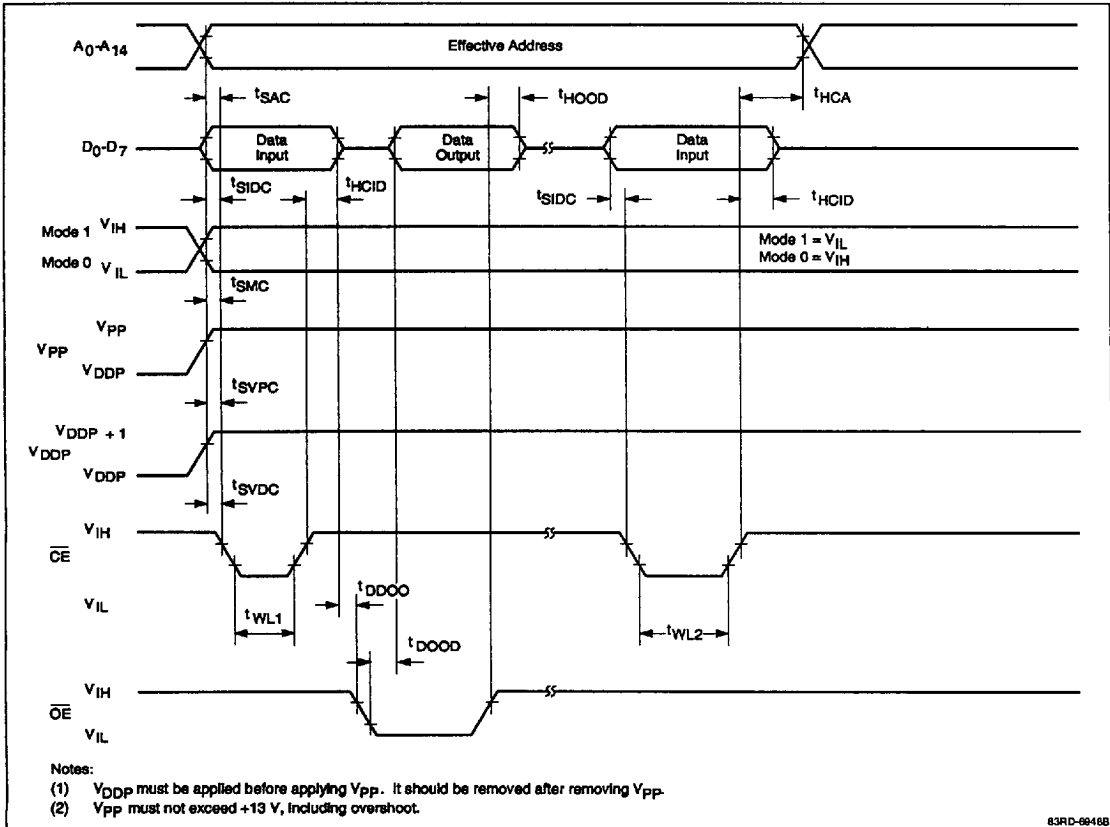
μPD78CP18 AC Programming Characteristics $T_A = 25 \pm 5^\circ\text{C}$; MODE1 = V_{IL} ; $V_{SS} = 0\text{ V}$

Parameter	Symbol	Symbol*	Min	Typ	Max	Unit	Condition
Address setup time to $\overline{CE} \downarrow$	t_{SAC}	t_{AS}	2			μs	
Data to $\overline{OE} \downarrow$ delay time	t_{DDO}	t_{OES}	2			μs	
Input data setup time to $\overline{CE} \downarrow$	t_{SIDC}	t_{DS}	2			μs	
Address hold time from $\overline{CE} \uparrow$	t_{HCA}	t_{AH}	2			μs	
Input data hold time from $\overline{CE} \uparrow$	t_{HCID}	t_{DH}	2			μs	
Output data hold time from $\overline{OE} \uparrow$	t_{HOOD}	t_{DF}	0		130	ns	
V_{PP} setup time to $\overline{CE} \downarrow$	t_{SVPC}	t_{VPS}	2			μs	
V_{DDP} setup time to $\overline{CE} \downarrow$	t_{SVDC}	t_{VDS}	2			μs	
Initial program pulse width	t_{WL1}	t_{PW}	0.95	1.0	1.05	ms	
Additional program pulse width	t_{WL2}	t_{OPW}	2.85		78.75	ms	
MODE0/MODE1 setup time vs. $\overline{CE} \downarrow$	t_{SMC}		2			μs	MODE1 = V_{IL} and MODE0 = V_{IH}
Address to data output time	t_{DAOD}	t_{ACC}			2	μs	$\overline{OE} = V_{IL}$
$\overline{CE} \downarrow$ to data output time	t_{DCOD}	t_{CE}			1	μs	
$\overline{OE} \downarrow$ to data output time	t_{DOOD}	t_{OE}			1	μs	
Data hold time from $\overline{OE} \uparrow$ or $\overline{CE} \uparrow$	t_{HCOD}	t_{DF}	0		130	ns	
Data hold time from address	t_{HAOD}	t_{OH}	0			ns	$\overline{OE} = V_{IL}$

* Corresponding symbols of the μPD27C256A.

PROM Timing Diagrams

μPD78CP18 PROM Write Mode



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μPD78C18 Family



PROM Timing Diagrams (cont)

μPD78CP18 PROM Read Mode

